

^{172}Hg α decay 2009Sa27, 2004Ke06, 1999Se14

Type	Author	History Citation	Literature Cutoff Date
Full Evaluation	Coral M. Baglin	NDS 111, 1807 (2010)	15-Jun-2010

Parent: ^{172}Hg : E=0.0; $J^\pi=0^+$; $T_{1/2}=231 \mu\text{s}$ 9; $Q(\alpha)=7525$ 6; % α decay≈100.0

2009Sa27: ^{172}Hg from $^{96}\text{Ru}(^{78}\text{Kr},2n)$, E=337-355 MeV; 96.52% ^{96}Ru target; RITU gas-filled separator; JUROGAM

Compton-suppressed Ge detector array (43 EUROGAM Phase I and GASP type detectors); fusion products implanted In double-sided Si strip detectors At focal plane of the GREAT spectrometer which also includes 28 Si PIN diodes, one segmented planar Ge detector and 3 clover Ge detectors; recoil decay tagging technique; measured $E\gamma$, $E\alpha$, recoil- $\alpha(t)$, parent-daughter α correlations.

2004Ke06: ^{172}Hg from $^{96}\text{Ru}(^{78}\text{Kr},2n)$, E=361-391 MeV, 96.52% ^{96}Ru target; RITU gas-filled separator with position-sensitive Si strip detector In focal plane; evaporation residues identified using method of position and time correlation with subsequent mother and daughter α decays; measured $E\alpha$, recoil- $\alpha(^{172}\text{Hg})-\alpha(^{168}\text{Pt})$ time correlation, ^{172}Hg and ^{168}Pt half-life.

1999Se14: ^{172}Hg source from $^{96}\text{Ru}(^{78}\text{Kr},2n)$, E=375 MeV; isotopically enriched target; fragment mass analyzer, double-sided Si strip detector, observed spatial and time correlations between fragment implantation and its decays; measured $E\alpha$, parent $T_{1/2}$.

Parent $T_{1/2}=231 \mu\text{s}$ 9 from 2009Sa27. other data: 0.25 ms +35–9 (1999Se14), 0.32 ms +32–11 (2004Ke06).

 ^{168}Pt Levels

$E(\text{level})$	$J^\pi{}^\dagger$
0.0	0^+

[†] From Adopted Levels.

 α radiations

$E\alpha$	$E(\text{level})$	$\text{HF}{}^\ddagger$	Comments
7350 6	0.0	1.0	<p>$E\alpha$: weighted average of 7350 12 (1999Se14) and 7361 14 (2004Ke06) and 7348 7 (2009Sa27). this $E\alpha$ implies $Q(\alpha)=7525$ 6 cf. 7525 12 In 2003Au03 and 2009AuZZ.</p> <p>Iα: only one α group was observed. Possible α decay to the 581.4-keV 2^+ excited state is estimated to be <1.4% of α decay by requiring its hindrance factor to be greater than 1.0. $I(7350\alpha)=99.3$ 7 per 100 α decays is used in the computation of the r_0 parameter.</p> <p>correlated with 6820α from ^{168}Pt and 6310α from ^{164}Os (2004Ke06).</p>

[†] $r_0=1.556$ 3 if % $\alpha(^{172}\text{Hg})=100$, assuming HF=1, $Q(\alpha)=7525$ 6 from measured $E\alpha=7350$ 6, $T_{1/2}(^{172}\text{Hg})=231 \mu\text{s}$ 9 (2009Sa27) and I α (to g.s.)=99.3 7 (based on possible branch to 2^+ 581 level of <1.4 for HF>1).